Total Pages : 03

Roll No.

BT-2/M-23 42033 SEMICONDUCTOR PHYSICS BS-115A

Time : Three Hours]

-46793-42033

[Maximum Marks: 75

Note: Attempt *Five* questions in all, selecting at least *one* question from each Unit. All questions carry equal marks.

Unit I

- (a) What is Bravais lattice ? Explain different types of Brvais lattices in three dimensions.
 7
 - (b) Discuss the hexagonal closed packed (hcp) structure and determine the c/a ratio for hcp structure.
- 2. (a) What do you mean by point defects in solids ?
 Derive an expression for concentration of Frankel defects at thermal equilibrium.
 8
 - Explain the different types of bonding in solids and give one example of each. 7

Unit II

 (a) Describe the de-Broglie matter waves and establish the correspondence between particle concepts and wave concepts. (b) Explain the group velocity and particle velocity.
 Prove that group velocity is less than the phase velocity in dispersive medium.

(a)

L-42033

- State Heisenberg's uncertainty principle. Prove the non-existence of the electron inside the nucleus using uncertainty principle. 7
- (b) Derive the time independent one-dimensional
 <u>Schrodinger</u> wave equation for s non-relativistic a free particle. Also give the significance of the wave function.

Unit III

- 5. (a) What are the drawbacks of classical free electron theory? Discuss the quantum theory of free electron in a one-dimensional box.
 - (b) Discuss the Fermi-Dirac distribution function. Plot this function for various temperatures including 0 K.
- 6. (a) Explain the concept of effective mass of the electron on the basis of band theory of solids. 7
 - (b) What is Hall effect ? Derive an expression for Hall coefficient and mention some of the applications of this effect.

Unit IV

- What are Semiconductors ? Explain the intrinsic and extrinsic semiconductors.
 - Derive an expression for carrier concentration in n-type semiconductors. What would be the position of Fermi level in the same ? 7
- 8. (a) What are Bipolar Junction Transistors (BJT)? Explain the characteristics of the bipolar junction transistors.
 8
 - Describe the principle, construction and working of a semiconductor laser. 7

3

(a)

(b)

(b)

7.